## NSN 5962-01-577-5367

Memory Microcircuit - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5962-01-577-5367 **Body Length:** 0.740 inches **Body Width:** Between 0.250 inches and 0.370 inches **Body Height:** Between 0.045 inches and 0.090 inches **Operating Tempurature Range:** -55.0/+125.0 degrees celsius **Storage Tempurature Range:** -65.0/+150.0 degrees celsius **End Application:** 26f aircraft, f-16; 43n aircraft, hornet f/a-18; vun aircraft, hornet f/a-1 (e/f); z9n aircraft, fa-18, a-d, e/f, g (growler) **Features Provided:** Monolithic and parallel operation **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Complementary-oxidized-silicon logic **Product Name:** Microcircuit, memory, digital, cmos, paralel 512 x 9 fifo, monolithic silicon **Voltage Rating And Type Per Characteristic:** 7.0 volts input **Time Rating Per Chacteristic:** 30.00 nanoseconds access **Memory Device Type:** First-in first-out **Memory Capacity:** 512 x 9 **Special Features:** Case outline: mil-std-1835, gdfp2-f28 **Terminal Type And Quantity:** 24 flat leads Shelf Life: N/a **Unit Of Measure:** 

Fiig:

A458a0

**Demilitarization:** Yes - demil/mli